

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	493	(257/365).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/08/08 10:55
L2	1	(vertical near2 junction adj1 field adj1 effect adj1 transistor) and (lateral near2 field adj1 effect adj1 transistor) and (silicon adj1 carbide adj1 substrate)	US-PGPUB; USPAT	OR	OFF	2006/08/08 10:58
L4	198	(257/134,135).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/08/08 10:58